

# INCHANGE SEMICONDUCTOR

# **isc** Silicon NPN Power Transistors

# KSC5021F

### DESCRIPTION

- Collector-Emitter Sustaining Voltage-: V<sub>CEO(SUS)</sub>= 500V(Min)
- Collector Current-I<sub>C</sub>= 5A(Max.)
- Low Collector Saturation Voltage
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

• Designed for use in drivers such as DC/DC converters and actuators.

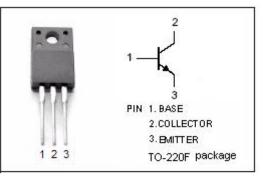
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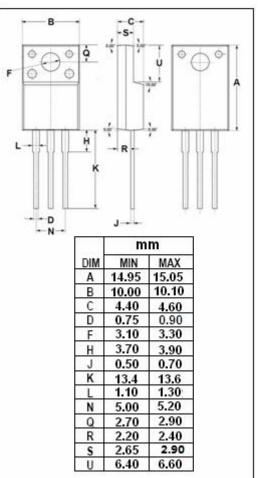
### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	800	v
$V_{\text{CEO}}$	Collector-Emitter Voltage	500	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	5	А
I <sub>CM</sub>	Collector Current-Peak	10	А
IB	Base Current-Continuous	2	А
Ρτ	Total Power Dissipation @ $T_c$ =25°C	40	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C

#### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	3.125	°C/W







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## ELECTRICAL CHARACTERISTICS

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 5mA; I <sub>B</sub> = 0	500			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.5	V
Ісво	Collector Cutoff Current	At rated Voltage			10	μA
I <sub>CEO</sub>	Collector Cutoff Current	At rated Voltage			10	μA
I <sub>EBO</sub>	Emitter Cutoff Current	At rated Voltage			10	μA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.6A; V <sub>CE</sub> = 5V	15		50	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 5V	8			
fT	Current-Gain—Bandwidth Product	Ic= 0.6A; Vce= 10V		15		MHz

#### h<sub>FE-1</sub> Classifications

R	ο	Y
15-30	20-40	30-50

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